

## Features

- Split Gate Trench MOSFET Technology
- Excellent Package for Heat Dissipation
- High Density Cell Design for Low  $R_{DS(ON)}$
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## Maximum Ratings

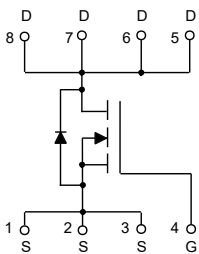
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 3.5°C/W Junction to Case<sup>(2)</sup>

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	40	V
Gate-Source Voltage	$V_{GS}$	±20	V
Continuous Drain Current	$I_D$	100	A
Pulsed Drain Current <sup>(3)</sup>	$I_{DM}$	320	A
Total Power Dissipation	$P_D$	35	W
Single Pulsed Avalanche Energy <sup>(4)</sup>	$E_{AS}$	720	mJ

Note:

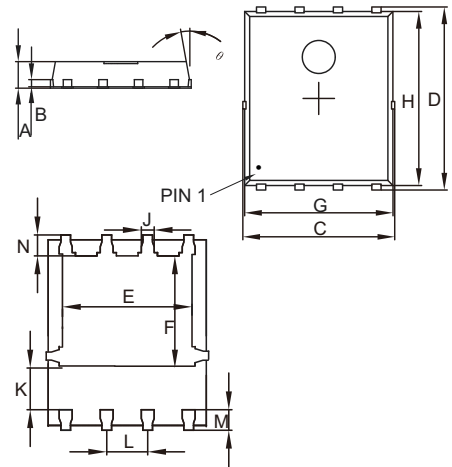
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. Surface Mounted on 1 in<sup>2</sup> pad area, t≤10 sec.
3. Pulse width≤300μs, duty cycle≤2%.
4.  $T_J=25^\circ\text{C}$ ,  $V_{DD}=40\text{V}$ , L=1mH.

## Internal Structure



# N-CHANNEL MOSFET

## DFN5060



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.031	0.047	0.80	1.20	
B	0.010		0.254		TYP.
C	0.193	0.222	4.90	5.64	
D	0.232	0.250	5.90	6.35	
E	0.148	0.167	3.75	4.25	
F	0.126	0.154	3.20	3.92	
G	0.189	0.213	4.80	5.40	
H	0.222	0.239	5.65	6.06	
K	0.045	0.059	1.15	1.50	
J	0.012	0.020	0.30	0.50	
L	0.046	0.054	1.17	1.37	
M	0.012	0.028	0.30	0.71	
N	0.016	0.028	0.40	0.71	

**Electrical Characteristics @ 25°C (Unless Otherwise Specified)**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	40			V
Gate-Source Leakage Current	$I_{GSS}$	$V_{DS}=0V, V_{GS}=\pm 20V$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=32V, V_{GS}=0V$			1	$\mu A$
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.5		2.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=20A$		1.8	2.2	m $\Omega$
		$V_{GS}=4.5V, I_D=10A$		2.4	3.2	m $\Omega$
<b>Diode Characteristics</b>						
Continuous Body Diode Current	$I_S$				100	A
Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V, I_S=20A$			1.3	V
Reverse Recovery Time	$t_{rr}$	$I_F=20A, di_F/dt=100A/\mu s$		67		ns
Reverse Recovery Charge	$Q_{rr}$			92		nC
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=20V, V_{GS}=0V, f=1MHz$		5005		pF
Output Capacitance	$C_{oss}$			1638		
Reverse Transfer Capacitance	$C_{rss}$			93		
Total Gate Charge	$Q_g$	$V_{DS}=20V, V_{GS}=10V, I_D=20A$		81		nC
Gate-Source Charge	$Q_{gs}$			18		
Gate-Drain Charge	$Q_{gd}$			15		
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=20V, V_{GEN}=10V, R_G=4.5\Omega, R_L=1\Omega, I_{DS}=20A$		16		ns
Turn-On Rise Time	$t_r$			48		
Turn-Off Delay Time	$t_{d(off)}$			75		
Turn-Off Fall Time	$t_f$			40		

**Curve Characteristics**

Fig. 1 - Typical Output Characteristics

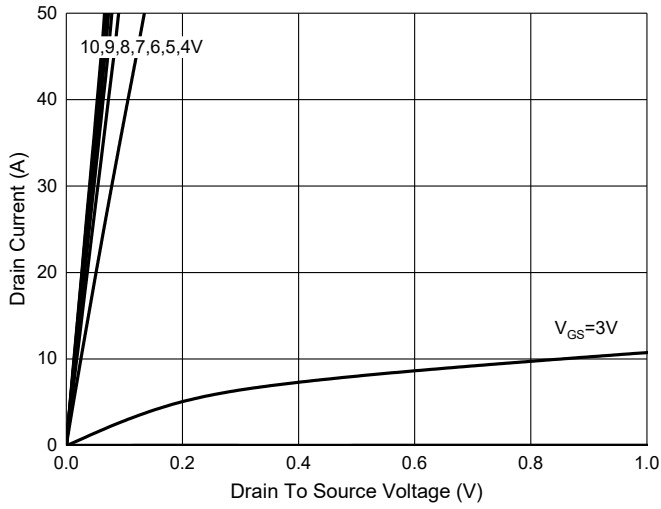


Fig. 2 -  $I_S - V_{SD}$

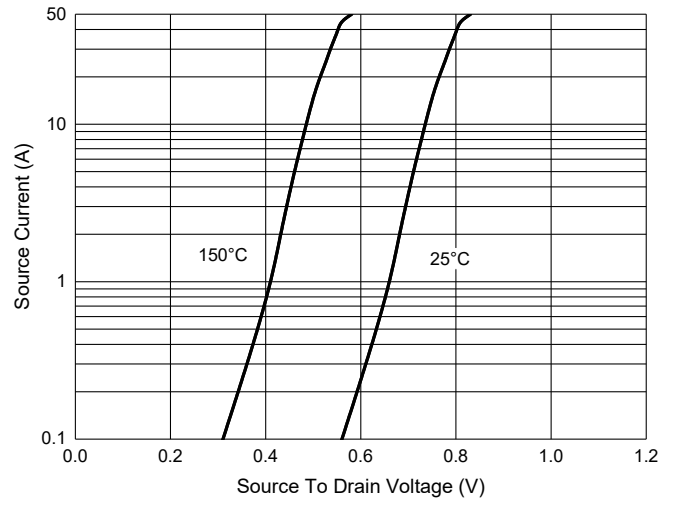


Fig. 3 -  $R_{DS(ON)} - I_D$

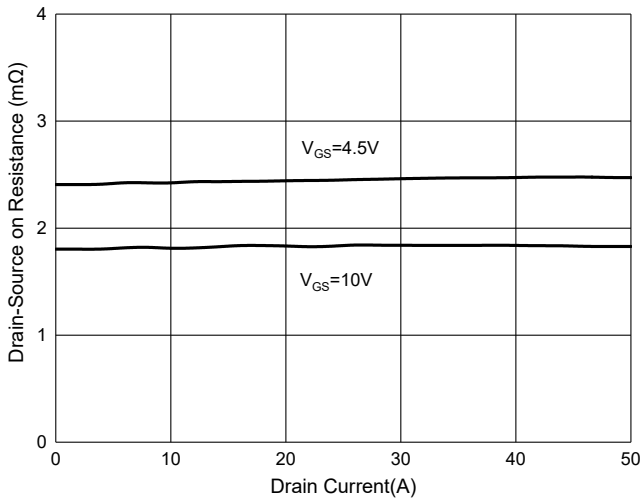


Fig. 4 - Normalized On Resistance Characteristics

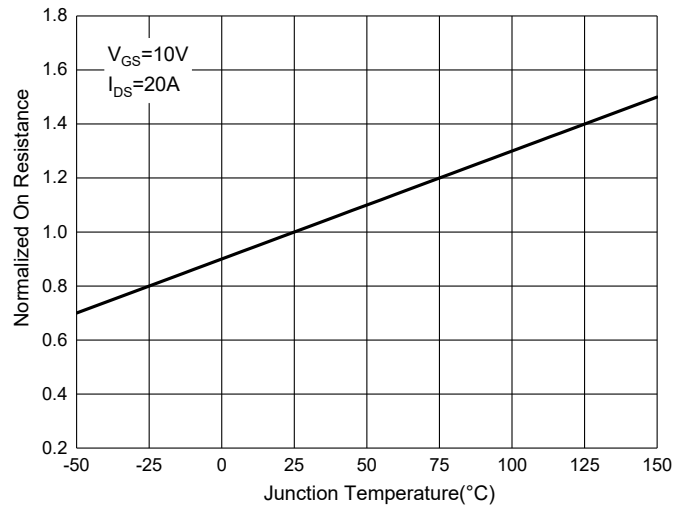


Fig. 5 - Capacitance Characteristics

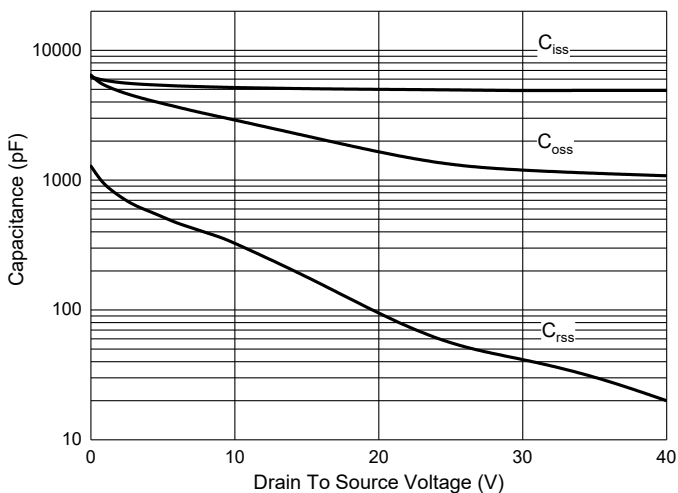
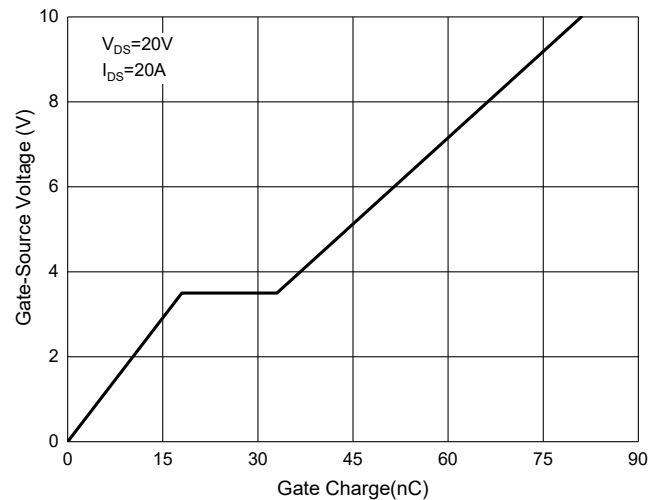


Fig. 6 - Gate Charge



Curve Characteristics

Fig. 7 - Safe Operation Area

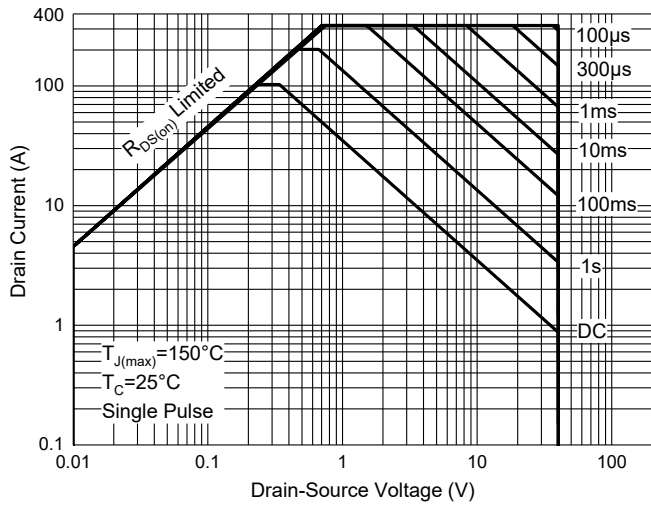
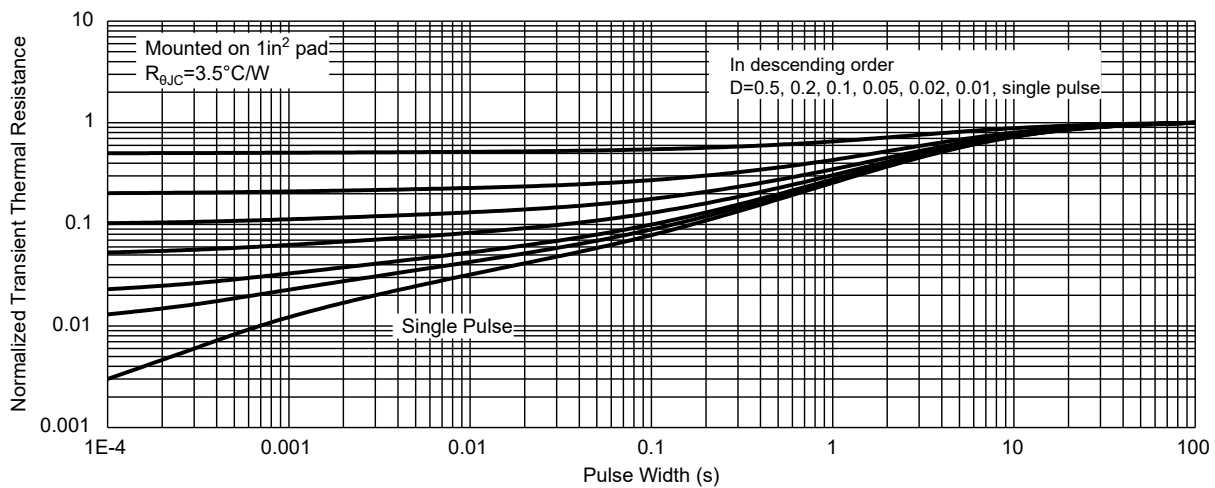


Fig. 8 - Normalized Maximum Transient Thermal Impedance



## Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 5Kpcs/Reel

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